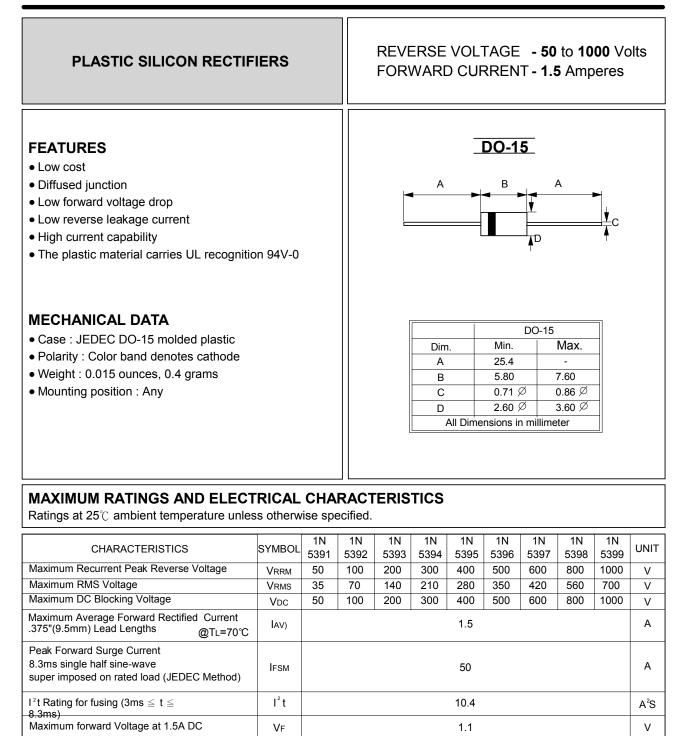
LITE ON SEMICONDUCTOR

1N5391 thru 1N5399



 Storage Temperature Range
 T_{STG}

 NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

@TJ=25°C

@TJ=100°C

IR

СJ

Røjl

ΤJ

REV. 5, Oct-2010, KDAD01

uA

pF

°C/W

°С

°C

50

50

20

26

-55 to +125

-55 to +150

2. Thermal Resistance Junction to Lead .

Maximum DC Reverse Current

at Rated DC Blocking Voltage

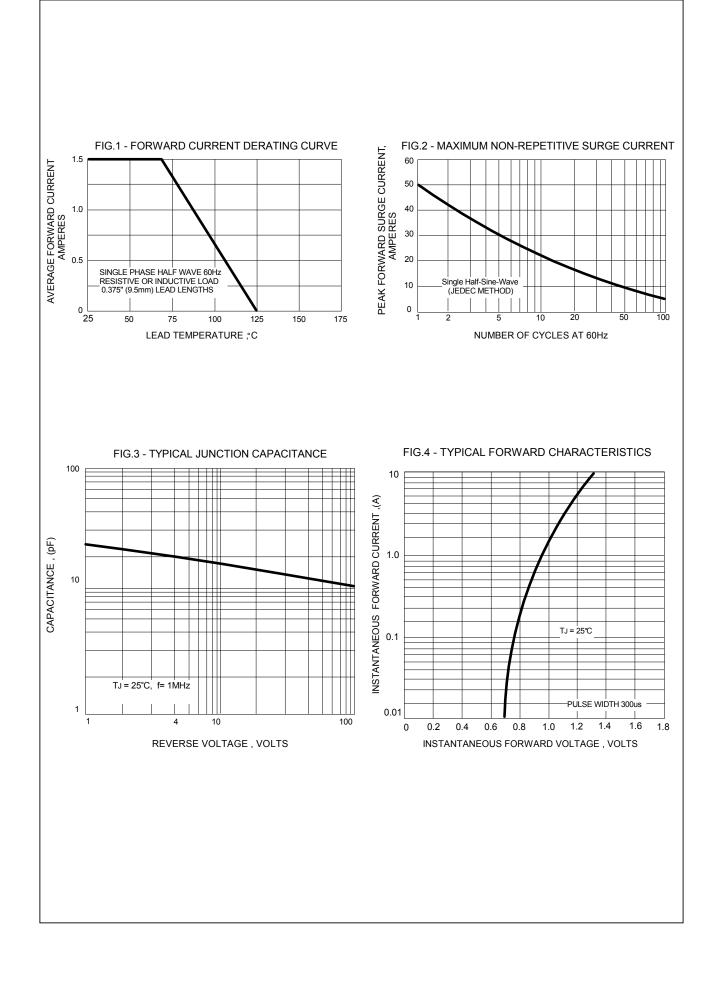
Operating Temperature Range

Typical Thermal Resistance (Note 2)

Typical Junction

Capacitance (Note 1)

RATING AND CHARACTERISTIC CURVES 1N5391 thru 1N5399



LITE ON



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